

View Online at <https://aerobasegroup.com/nsn/5961-01-106-4654>

**Inclosure Material:**

Plastic

**Overall Length:**

0.785 inches

**Overall Height:**

0.200 inches

**Overall Width:**

0.375 inches

**Component Name And Quantity:**

4 transistor

**Mounting Method:**

Press fit

**Features Provided:**

Burn in and hermetically sealed case

**Semiconductor Material:**

Silicon all transistor

**Voltage Rating In Volts Per Characteristic:**

60.0 collector to base voltage/static/emitter open all transistor and 40.0 collector to emitter voltage/static/base open all transistor and 5.0 emitter to base voltage, instantaneous all transistor

**Current Rating Per Characteristic:**

500.00 milliamperes source cutoff current all transistor

**Power Rating Per Characteristic:**

1900.0 milliwatts small-signal input power, common-collector preset all transistor

**Maximum Operating Temperature Per Measurement Point:**

200.0 degrees celsius junction

**Special Features:**

All transistor junction pattern arrangement: npn

**Terminal Type And Quantity:**

12 ribbon

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fig:**

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